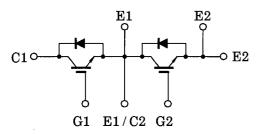
TOSHIBA GTR Module Silicon N Channel IGBT

# MG150Q2YS51

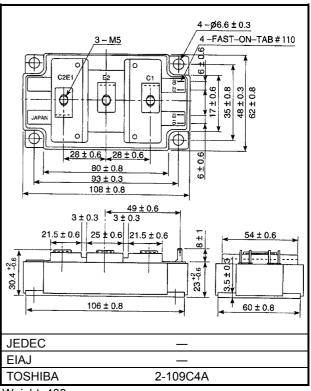
High Power Switching Applications Motor Control Applications

- High input impedance
- High speed  $: t_f = 0.3 \mu s (Max)$ @Inductive Load
- Low saturation voltage
  - $: V_{CE (sat)} = 3.6 V (Max)$
- Enhancement-mode
- Includes a complete half bridge in one package.
- The electrodes are isolated from case.

#### **Equivalent Circuit**



#### Maximum Ratings (Ta = 25°C)



Weight: 430g

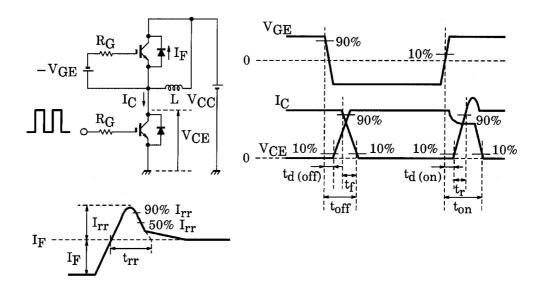
Characteristic		Symbol	Rating	Unit	
Collector-emitter voltage		V <sub>CES</sub>	1200	V	
Gate-emitter voltage		V <sub>GES</sub>	±20	V	
Collector current	DC	I <sub>C</sub> (25°C / 80°C)	200 / 150	A	
	1ms	I <sub>CP</sub> (25°C / 80°C)	400 / 300		
Forward current	DC	١ <sub>F</sub>	150	A	
	1ms	I <sub>FM</sub>	300		
Collector power dissipation (Tc = 25°C)		Pc	1250	W	
Junction temperature		Tj	150	°C	
Storage temperature range		T <sub>stg</sub>	-40 ~ 125	°C	
Isolation voltage		V <sub>Isol</sub>	2500 (AC 1 min.)	V	
Screw torque (Terminal / mounting)		—	3 / 3	N∙m	

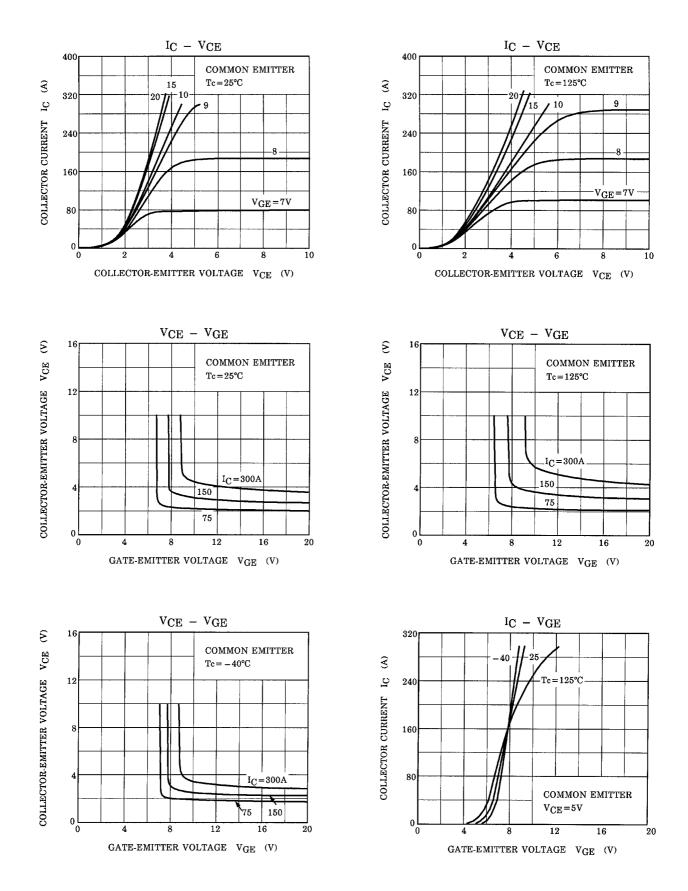
Unit: mm

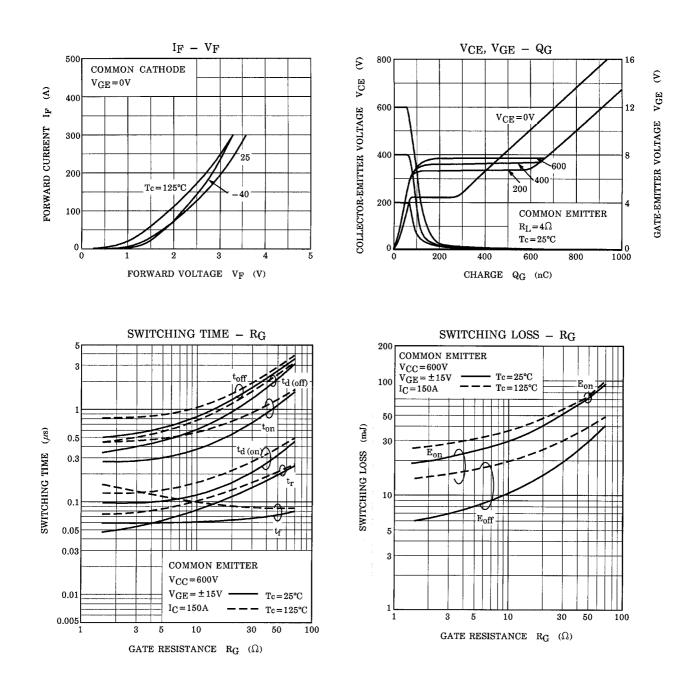
**Electrical Characteristics (Ta = 25°C)** 

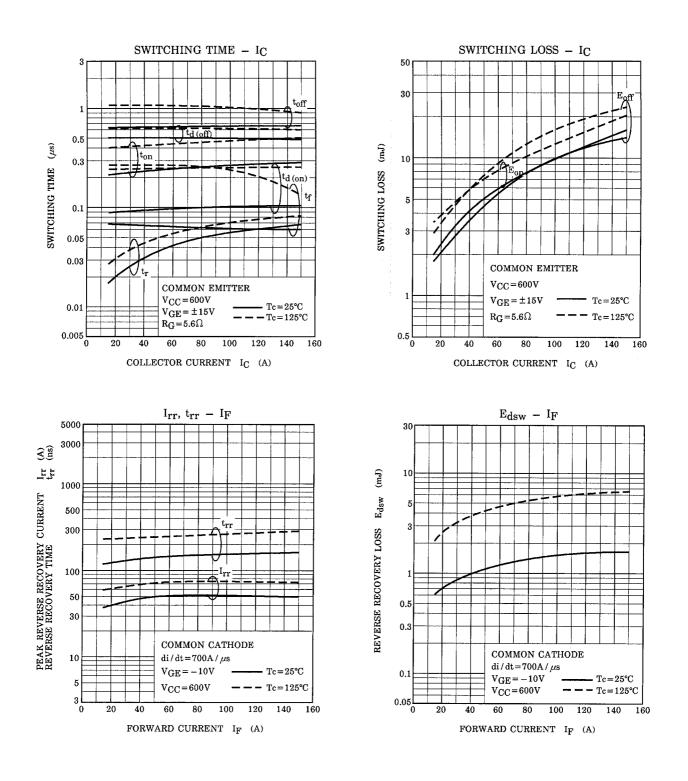
Cha	racteristic	Symbol	col Test Condition		Min	Тур.	Max	Unit
Gate leakage current		I <sub>GES</sub>	$V_{GE}$ = ±20V, $V_{CE}$ = 0		_	_	±500	nA
Collector cut-off current		ICES	V <sub>CE</sub> = 1200V, V <sub>GE</sub> = 0		_	_	2.0	mA
Gate-emitter cut-off voltage		V <sub>GE (off)</sub>	I <sub>C</sub> = 150mA, V <sub>CE</sub> = 5V		3.0	_	6.0	V
Collector-emitter saturation voltage		V <sub>CE (sat)</sub>	I <sub>C</sub> = 150A, V <sub>GE</sub> = 15V	T <sub>j</sub> = 25°C	_	2.8	3.6	v
				T <sub>j</sub> = 125°C	_	3.1	4.0	
Input capacitance		Cies	V <sub>CE</sub> = 10V, V <sub>GE</sub> = 0, f = 1MHz		_	18.0	_	nF
Switching time	Turn-on delay time	t <sub>d(on)</sub>			_	0.05	_	
	Rise time	t <sub>r</sub>	Inductive load		_	0.05	_	μs
	Turn-on time	t <sub>on</sub>	V <sub>CC</sub> = 600V I <sub>C</sub> = 150A		_	0.2	_	
	Turn-off delay time	t <sub>d(off)</sub>	V <sub>GE</sub> = ±15V R <sub>G</sub> = 5.6Ω		_	0.5	_	
	Fall time	t <sub>f</sub>	(Note		_	0.1	0.3	
	Turn-off time	t <sub>off</sub>			_	0.6	_	
Forward voltage		V <sub>F</sub>	I <sub>F</sub> = 150A, V <sub>GE</sub> = 0		_	2.4	3.5	V
Reverse recovery time		t <sub>rr</sub>	I <sub>F</sub> = 150A, V <sub>GE</sub> = -10V di / dt = 700A / μs (Note 1)		_	0.1	0.25	μs
Thermal resistance		R <sub>th (j-c)</sub>	Transistor stage		_	_	0.1	°C/W
			Diode stage		_	_	0.24	

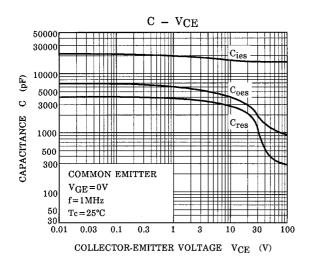
Note 1: Switching time and reverse recovery time test circuit & timing chart

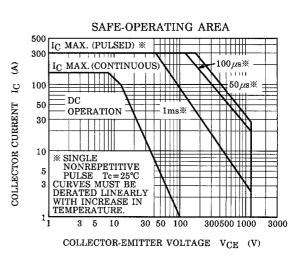


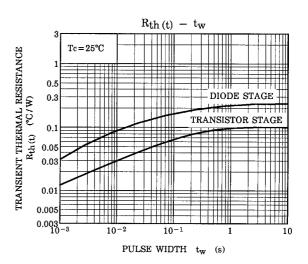


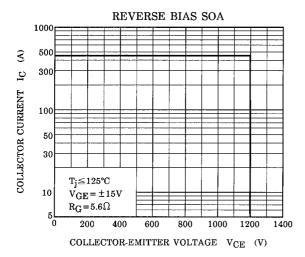


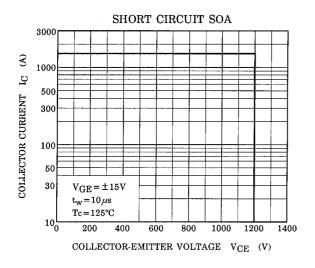












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